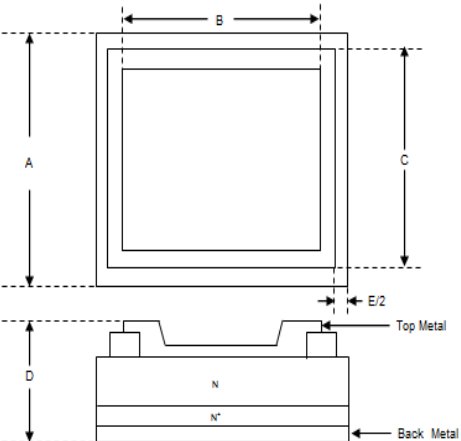




TSB82T100S(A)S-255C

10A/100V⁽¹⁾, low VF Schottky barrier diode with trench MOS structure

Mechanical Data

Chip Drawing	Item	Information	
	Die Size (A)	2082 μm	82 mil
	Top Metal Pad Size (B)	1950 μm	77mil
	Chip Size (C)	2002 μm	79mil